Absorptive DT RF Switch

50Ω 500-6000 MHz

ZFSWA2-63DR+

The Big Deal

- Wide bandwidth 500 to 6000 MHz
- Very high isolation, 65 dB at 1GHz
- Very fast switching, 35ns
- Rugged case with internal hermetically sealed ceramic semi-conductor module



Product Overview

The ZFSWA2-63DR+ is a great general purpose SPDT solid state absorptive RF switch. With its broad frequency range, fast 35 ns switching time and excellent RF performance, the ZFSWA2-63DR+ is an excellent choice for many applications. In addition to it's versatility within system block diagrams, the ZFSWA2-63DR+ is designed for easy integration into your prototype design applications.

Note: This model is same as ZFSWA2R-63DR+ except RF1 and RF2 ports are interchanged.

Key Features

| Feature | Advantages | | | | | | |
|---|---|--|--|--|--|--|--|
| Designed for any environment | The ZFSWA2-63DR+ is equipped with a rugged shielded case, a hermetically sealed internal device with a wide operating temperature range (-55°C to 100°C) Suitable for many environments and applications the ZFSWA2-63DR+ offers excellent performance and value | | | | | | |
| Integrated CMOS Driver | -Operates from 3-5V -Low control current 5 µA allows compatibility with a variety of driver circuits -Internal Decoupling -Fast 35 ns Switching time | | | | | | |
| Excellent for a Variety of Applications From Bench to Integrated Systems | -High speed testers -Automated switching networks -Wireless Infrastructure -Military | | | | | | |
| Excellent RF Performance | -Wide bandwidth: 500 to 6000 MHz -Low Insertion Loss: 1.4 dB Typ -High Isolation: 65 dB Typ @ 1 GHz | | | | | | |

Notes

A Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document. B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions. C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuit's website at www.minicircuits.com/MCLStore/terms.jsp



Coaxial **SPDT RF Switch**

Absorptive RF Switch with Internal Driver Single Supply Voltage, +3V to +5V

Product Features

- Wide bandwidth, 500 to 6000 MHz
- High Isolation, 65 dB typ. at 1 GHz
- Low Insertion loss, 1.4 dB typ.
- Internal CMOS driver
- Fast switching, Rise/fall time, 25 ns typ.
- Built rugged for tough environments
- Wide operating temperature, -55°C to 100°C





CASE STYLE: ZZ1322

Connectors Model SMA ZFSWA2-63DR+ **BRACKET (OPTION "B")**

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

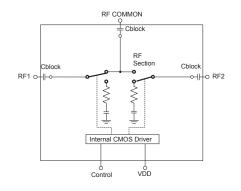
Typical Applications

- Cellular
- ISM, WCDMA, WIMAX
- PCN
- Automated switching networks
- Military

General Description

The ZFSWA2-63DR+ is a 50Ω high isolation, absorptive SPDT RF switch designed for wireless applications, covering a broad frequency range from 500 to 6000 MHz with low insertion loss. The ZFSWA2-63DR+ operates on a single supply voltage in the range of +3V to +5V. This unit includes an internal CMOS driver. The ZFSWA2-63DR+ switch comes in a rugged built case for tough environments.

Schematic and Application Circuit



Notes

A Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document. B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions. C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuit's website at www.minicircuits.com/WCLStore/terms.jsp



REV. G M170171 ZFSWA2-63DR+ IG/CP/AM 200817 Page 2 of 5

RF Electrical Specifications, 500 - 6000 MHz, T_{AMB}=25°C, V_{DD}= +3V to +5V

| Parameter | Condition | Min. | Тур. | Max. | Units | | |
|---|--|---------------------|-----------|-----------------|------------|--|--|
| Frequency Range | | 500 | | 6000 | MHz | | |
| | 500 MHz | | 1.0 | 1.3 | | | |
| | 1000 MHz | | 1.15 | 1.5 | | | |
| Insertion Loss | 2000 MHz | | 1.4 | 1.7 | dB | | |
| | 4000 MHz | | 1.7 | 2.1 | | | |
| | 6000 MHz | 50 | 2.0 65 | 2.6 | | | |
| Isolation between Common port and RF1/RF2 Ports | 500 to 2000 MHz 2000 to 4000 MHz | 50 48 | 57 | | dB | | |
| isolation between common port and rit 1/rit 2 Ports | 4000 to 6000 MHz | 40 35 | 45 | | UD | | |
| | 500 to 2000 MHz | 50 | 60 | | | | |
| Isolation between RF1 and RF2 ports | 2000 to 4000 MHz | 43 | 50 | | dB | | |
| · | 4000 to 6000 MHz | 35 | 45 | | | | |
| | 500 to 2000 MHz | | 20 | | | | |
| Return Loss (ON STATE) | 2000 to 4000 MHz | | 17 | | dB | | |
| | 4000 to 6000 MHz | | 15 | | | | |
| | | 500 to 2000 MHz 17 | | | | | |
| Return Loss @ RF1/RF2 ports (OFF STATE) | | 2000 to 4000 MHz 19 | | | | | |
| | 4000 to 6000 MHz V _{DD} =3V, 500 to 2000 MHz | | 16 47 | | | | |
| | 2000 to 6000 MHz | | 47 | | | | |
| Input IP3 | V _{DD} =5V, 500 to 2000 MHz | | 49 | | dBm | | |
| | 2000 to 6000 MHz | | 44 | | | | |
| | V _{DD} =3V, 500 to 2000 MHz | | 24 | | | | |
| Input 1dB Compression ⁽¹⁾ | 2000 to 6000 MHz | 24 | | dBm | | | |
| Input TdB Compression (*) | V_{DD} =5V, 500 to 2000 MHz | | 30 | | UDITI | | |
| | 2000 to 6000 MHz | | 27 | | | | |
| I | DC Electrical Specification | s | | | | | |
| VDD, Supply Voltage | | 3 | | 5 | V | | |
| Supply Current ⁽²⁾ | V _{DD} =5V | | 50 | | μΑ | | |
| Control Voltage Low | | 0 | | 0.5 | V | | |
| Control Voltage High ⁽³⁾ | | 2.7 ⁽⁴⁾ | | V _{DD} | V | | |
| Control Current | | | 5 | | μΑ | | |
| | Switching Specifications | | | | | | |
| Rise/Fall Time (10 to 90% or 90 to 10% RF) | V _{DD} =5V | | 25 | | nSec | | |
| Switching Time (50% CTRL to 90/10% RF) | V _{DD} =5V | | 35 | | nSec | | |
| Video Feed through (Control 0-5V, Frequency 1 MHz) | V _{DD} =5V | | 30 | | mV_{P-P} | | |

Notes:

Note absolute maximum rating for input and dissipated power. At 5V, over 2000-6000 MHz, 0.2 dB compression.
Increases with switching repetition rate. See graph.

3. CMOS interface latch-up condition may occur when logic high signal is applied prior to power supply.

4. 3.5V for V_{DD} =4 to 5V

Absolute Maximum Ratings

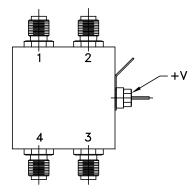
| Parameter Ratings Operating Temperature -55°C to 100°C Storage Temperature -55°C to 100°C Vob, Supply Voltage 2.7 to 5.5V Voltage Control -0.2V Min. Vpb Max. RF input power 1Watt Dissipated Power at 25°C 370mW ESD, HBM Class 1A (250 to <500V) per JESD22-A114 ESD, CDM Class III (500 to <1000V) per JESD22-C101 | | | | | | | | | | |
|---|----------------------------------|---|--|--|--|--|--|--|--|--|
| Storage Temperature 55°C to 100°C V _{DD} , Supply Voltage 2.7 to 5.5V Voltage Control -0.2V Min. V _{DD} Max. RF input power 1Watt Dissipated Power at 25°C 370mW ESD, HBM Class 1A (250 to <500V) per JESD22-A114 ESD, MM Class A (passes 50V) per JESD22-A115 | Parameter | Ratings | | | | | | | | |
| VDD, Supply Voltage 2.7 to 5.5V Voltage Control -0.2V Min. VDD Max. RF input power 1Watt Dissipated Power at 25°C 370mW ESD, HBM Class 1A (250 to <500V) per JESD22-A114 | Operating Temperature | -55°C to 100°C | | | | | | | | |
| Voltage Control -0.2V Min. V _{DD} Max. RF input power 1Watt Dissipated Power at 25°C 370mW ESD, HBM Class 1A (250 to <500V) per JESD22-A114 | Storage Temperature | -55°C to 100°C | | | | | | | | |
| RF input power 1Watt Dissipated Power at 25°C 370mW ESD, HBM Class 1A (250 to <500V) per JESD22-A114 | V _{DD} , Supply Voltage | 2.7 to 5.5V | | | | | | | | |
| Dissipated Power at 25°C 370mW ESD, HBM Class 1A (250 to <500V) per JESD22-A114 | Voltage Control | -0.2V Min. V _{DD} Max. | | | | | | | | |
| ESD, HBM Class 1A (250 to <500V) per JESD22-A114 ESD, MM Class A (passes 50V) per JESD22-A115 | RF input power | 1Watt | | | | | | | | |
| ESD, MM Class A (passes 50V) per JESD22-A115 | Dissipated Power at 25°C | 370mW | | | | | | | | |
| | ESD, HBM | Class 1A (250 to <500V) per JESD22-A114 | | | | | | | | |
| ESD, CDM Class III (500 to <1000V) per JESD22-C101 | ESD, MM | Class A (passes 50V) per JESD22-A115 | | | | | | | | |
| | ESD, CDM | Class III (500 to <1000V) per JESD22-C101 | | | | | | | | |

Notes
A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
C. The parts covered by this specification document are subject to Mini-Circuit standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp

Truth Table (State of control voltage selects the desired switch state)

| State of Control Voltage | Switch State - RF Common to | | | | | | |
|--|-----------------------------|-----|--|--|--|--|--|
| State of Control Voltage | RF1 | RF2 | | | | | |
| Low | ON | OFF | | | | | |
| High | OFF | ON | | | | | |
| ON- low insertion loss state OFF- Isolation State | | | | | | | |

Coaxial Configuration



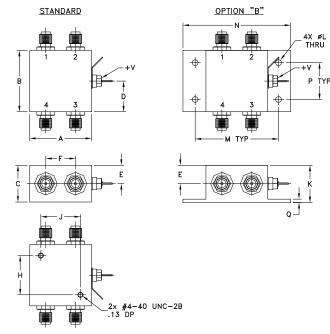
Coaxial Connections

| Function | Port Number | Description |
|----------|----------------|----------------------|
| RF COM | 1 | RF Common/ SUM Port |
| RF1 | 4 | RF Out #1/In Port #1 |
| RF2 | 3 | RF Out #2/In Port #2 |
| Control | 2 | CMOS Control IN |
| VDD | V+ | Supply Voltage |
| GND | Case | RF Ground |

Notes
A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
C. The parts covered by this specification document are subject to Mini-Circuit's standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuit's website at www.minicircuits.com/MCLStore/terms.jsp



Outline Drawing (ZZ1322)



Outline Dimensions (inch)

| | Α | В | С | D | Е | F | G | н | J | K | L | Μ | N | Р | Q | wt |
|----|------|-------|-------|-------|------|-------|---|-------|-------|-------|-------|-------|-------|-------|------|-------|
| 1 | 1.25 | 1.25 | 0.75 | 0.63 | 0.38 | 0.6 | | 0.800 | 0.800 | 0.76 | 0.125 | 1.688 | 2.18 | 0.75 | 0.07 | grams |
| 31 | .75 | 31.75 | 19.05 | 16.00 | 9.65 | 15.24 | | 20.32 | 20.32 | 19.30 | 3.18 | 42.88 | 55.37 | 19.05 | 1.78 | 85 |

Additional Detailed Technical Information

Additional information is available on our web site. To access this information enter the model number on our web site home page.

Performance data, graphs

Case Style: ZZ1322

Environmental Ratings: ENV28

Pricing & Availability Information

Notes

A Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document. B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions. C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuit's website at www.minicircuits.com/MCLStore/terms.jsp

